DATA SHEET



NPN SILICON GERMANIUM RF TRANSISTOR

NESG220034

NPN SiGE RF TRANSISTOR FOR UHF-BAND, LOW NOISE, LOW DISTORTION AMPLIFICATION 3-PIN POWER MINIMOLD (34 PKG)

FEATURES

- The device is an ideal choice for low noise, low distortion amplification.
 - NF = 0.7 dB TYP. @ $V_{CE} = 5 \text{ V}$, $I_{C} = 10 \text{ mA}$, f = 1 GHz
- Po (1 dB) = 22.5 dBm TYP. @ $V_{CE} = 5 V$, $I_{C (set)} = 40 mA$, f = 1 GHz
- OIP3 = 35 dBm TYP. @ VCE = 5 V, Ic (set) = 40 mA, f = 1 GHz
- Maximum stable power gain: MSG =12.5 dB TYP. @ VcE = 5 V, Ic = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS2): f_T = 11.5 GHz
- This product is improvement of ESD of NESG2xxx series.
- 3-pin power minimold (34 PKG)

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG220034	NESG220034-A	3-pin power minimold (34 PKG) (Pb-Free)	25 pcs (Non reel)	Magazine case
NESG220034-T1	NESG220034-T1-A		1 kpcs/reel	12 mm wide embossed tapingPin 2 (Collector) face the perforation side of the tape

Remark To order evaluation samples, please contact your nearby sales office. Unit sample quantity is 25 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vcво	5.5	V
Collector to Emitter Voltage	Vces	13	V
Collector to Emitter Voltage	Vceo	5.5	V
Base Current Note 1	Ів	36	mA
Collector Current	lc	200	mA
Total Power Dissipation	Ptot Note 2	886	mW
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-65 to +150	°C

Notes 1. Depend on the ESD protect device.

2. Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB

THERMAL RESISTANCE (TA = +25°C)

Parameter Symbol Ratings Unit

Termal Resistance from Junction to Ambient Note 141 °C/W

Note Mounted on 3.8 cm \times 9.0 cm \times 0.8 mm (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (TA = +25°C)

Parameter Symbol MIN. TYP. MAX. Unit
Collector Current Ic - 40 - mA

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ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	_	_	100	nA
Emitter Cut-off Current	ІЕВО	V _{EB} = 0.4 V, I _C = 0 mA	_	_	100	nA
DC Current Gain	hfe Note 1	VcE = 5 V, Ic = 10 mA	140	180	260	_
RF Characteristics	_		_	_	_	_
Gain Bandwidth Product	f⊤	VcE = 5 V, Ic = 40 mA, f = 1 GHz	_	11.5	-	GHz
Insertion Power Gain	S _{21e} ²	VcE = 5 V, Ic = 40 mA, f = 1 GHz	9.5	11.5	-	dB
Noise Figure (1)	NF1	$V_{\text{CE}} = 5 \text{ V, Ic} = 10 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, \ Z_{\text{L}} = 50 \Omega$	-	0.7	1.1	dB
Noise Figure (2)	NF2	$V_{CE} = 5 \text{ V}, \text{ Ic} = 40 \text{ mA}, \text{ f} = 1 \text{ GHz},$ $Z_{S} = Z_{Sopt}, Z_{L} = Z_{Lopt}$	-	0.9	-	dB
Associated Gain (1)	Ga1	$V_{\text{CE}} = 5 \text{ V, I}_{\text{C}} = 10 \text{ mA, f} = 1 \text{ GHz,}$ $Z_{\text{S}} = Z_{\text{Sopt}}, Z_{\text{L}} = 50 \Omega$	8.5	10.5	-	dB
Associated Gain (2)	Ga2	$V_{\text{CE}} = 5 \text{ V, Ic} = 40 \text{ mA, f} = 1 \text{ GHz},$ $Z_{\text{S}} = Z_{\text{Sopt}}, Z_{\text{L}} = Z_{\text{Lopt}}$	-	12.0	-	dB
Reverse Transfer Capacitance	Cre Note 2	V _{CB} = 5 V, I _E = 0 mA, f = 1 MHz	_	0.9	1.1	pF
Maximum Stable Power Gain	MSG Note 3	VcE = 5 V, Ic = 40 mA, f = 1 GHz	11.0	12.5	_	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\begin{aligned} &V_{\text{CE}} = 5 \text{ V, Ic}_{\text{(set)}} = 40 \text{ mA, f} = 1 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{aligned}$	-	22.5	ı	dBm
Output 3rd Order Intercept Point	OIP ₃	$\label{eq:Vce} \begin{split} &\text{Vce} = 5 \text{ V, Ic }_{\text{(set)}} = 40 \text{ mA, f} = 1 \text{ GHz,} \\ &\textit{\Delta} f = 1 \text{ MHz, } Z_S = Z_{\text{Sopt, }} Z_L = Z_{\text{Lopt}} \end{split}$	-	35	-	dBm

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded.

3. MSG =
$$\frac{S_{21}}{S_{12}}$$

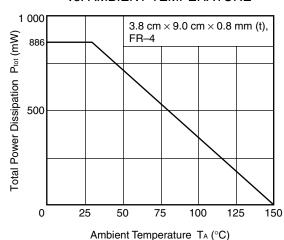
hfe CLASSIFICATION

Rank	FB		
Marking	SS		
h _{FE} Value	140 to 260		

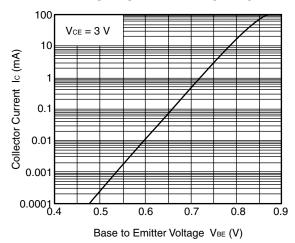
3

<R> TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

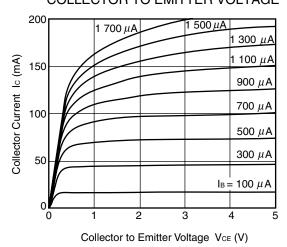
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

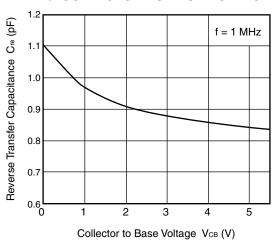


COLLECTOR CURRENT vs.
COLLECTOR TO EMITTER VOLTAGE

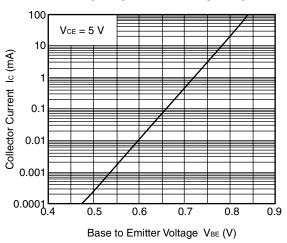


Remark The graphs indicate nominal characteristics.

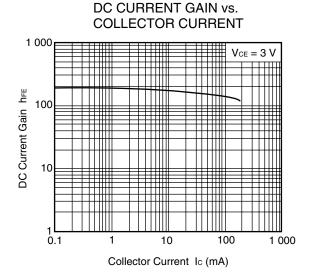
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE

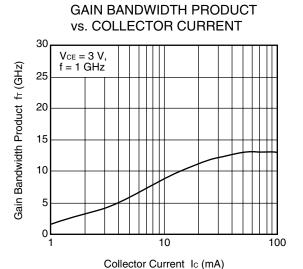


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

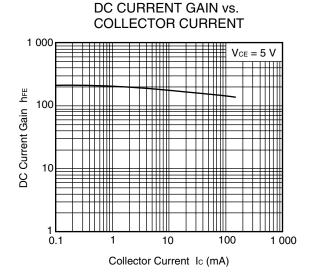


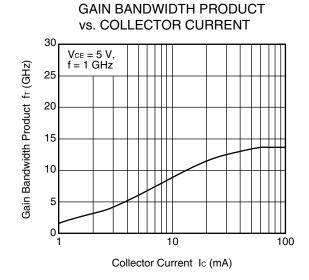




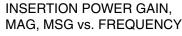


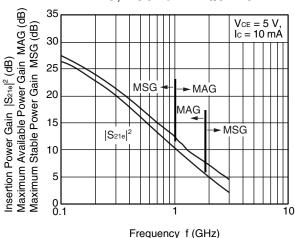
Remark The graphs indicate nominal characteristics.



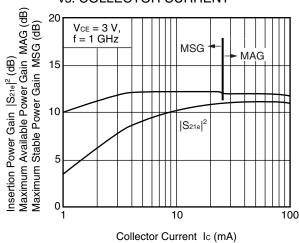


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY Maximum Available Power Gain MAG (dB) 35 $V_{CE} = 3 V$ Maximum Stable Power Gain MSG (dB) Ic = 10 mÅ30 Insertion Power Gain |S21e|2 (dB) 25 MSG MAG 20 MAG 15 |S_{21e}|² 10 5 0.1 1 10 Frequency f (GHz)



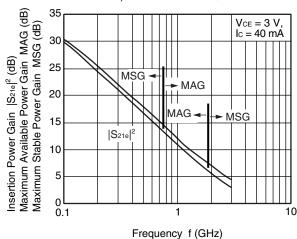


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

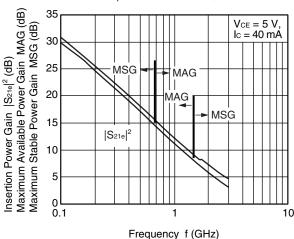


Remark The graphs indicate nominal characteristics.

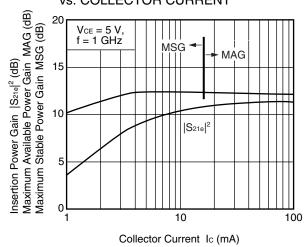
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



Noise Figure NF (dB)

0

vs. COLLECTOR CURRENT 16 VCE = 5 V, f = 1 GHz, 14 $Zs = Z_{Sopt}, Z_L = 50 \Omega$ G_a (dB) 12 Ga 10 Associated Gain

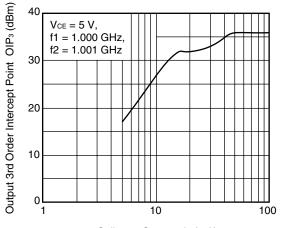
NF

100

NOISE FIGURE, ASSOCIATED GAIN

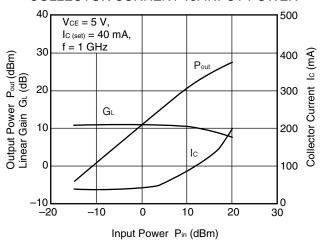
10 Collector Current Ic (mA)

OUTPUT 3RD ORDER INTERCEPT POINT vs. COLLECTOR CURRENT

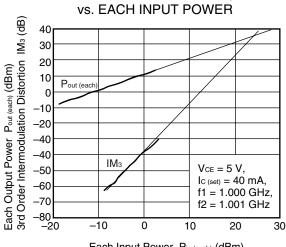


Collector Current Ic (mA)

OUTPUT POWER, LINEAR GAIN, COLLECTOR CURRENT vs. INPUT POWER



EACH OUTPUT POWER, IM3



Each Input Power Pin (each) (dBm)

Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

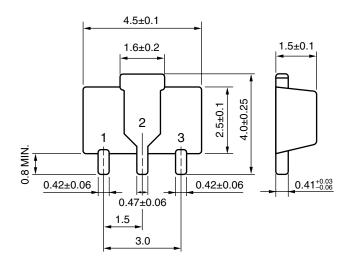
Click here to download S-parameters.

[RF and Microwave] \rightarrow [Device Parameters]

URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN POWER MINIMOLD (34 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
- 2. Collector
- 3. Base

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